

NE3519M04

R09DS0008EJ0100 Rev.1.00 Oct 21, 2010

N-channel GaAs HJ-FET, L to C Band Low Noise Amplifier

FEATURES

- Low noise figure and high associated gain NF = 0.40 dB TYP., G_a = 18.5 dB TYP. $@V_{DS}$ = 2 V, I_D = 10 mA, f = 2 GHz
- Flat-lead 4-pin thin-type super minimold (M04) package

APPLICATIONS

- Satellite radio (SDARS, etc.)
- Low noise amplifier for microwave communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3519M04-T2	NE3519M04-T2-A	Flat-lead 4-pin	3 kpcs/reel	V85	Embossed tape 8 mm wide
		thin-type super			Pin 1 (Source), Pin 2 (Drain)
NE3519M04-T2B	NE3519M04-T2B-A	minimold (M04)	15 kpcs/reel		face the perforation side of
		(Pb-Free)			the tape

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: NE3519M04

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	V_{DS}	4.0	V
Gate to Source Voltage	V_{GS}	-3.0	V
Drain Current	I _D	I _{DSS}	mA
Gate Current	I_{G}	200	μΑ
Total Power Dissipation Note	P _{tot}	150	mW
Channel Temperature	T _{ch}	+150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note: Mounted on 1.08 cm² \times 1.0 mm (t) glass epoxy PWB

CAUTION

Observe precautions when handling because these devices are sensitive to electrostatic discharge.

RECOMMENDED OPERATING RANGE ($T_A = +25^{\circ}C$)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	V_{DS}	_	2	3	V
Drain Current	I _D	_	10	25	mA
Input Power	P _{in}	_	_	0	dBm

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

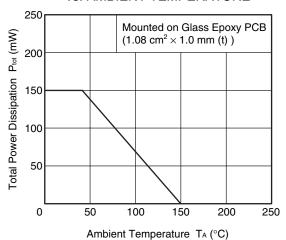
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I _{GSO}	$V_{GS} = -3.0 \text{ V}$	_	0.5	10	μΑ
Saturated Drain Current	I _{DSS}	$V_{DS} = 2 V$, $V_{GS} = 0 V$	30	45	60	mA
Gate to Source Cutoff Voltage	V _{GS (off)}	$V_{DS} = 2 \text{ V}, I_{D} = 50 \mu\text{A}$	-0.25	-0.50	-0.75	V
Transconductance	g _m	V _{DS} = 2 V, I _D = 10 mA	80	_	-	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 10 mA, f = 2 GHz	-	0.40	0.70	dB
Associated Gain	Ga		16.5	18.5	_	dB

STANDARD CHARACTERISTICS FOR REFERENCE (T_A = +25°C, unless otherwise specified)

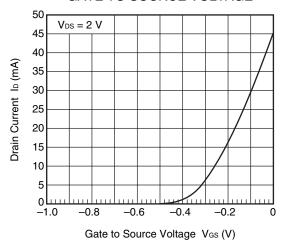
Parameter	Symbol	Test Conditions	Reference Value	Unit
Gain 1 dB Compression Output	P _{O (1 dB)}	V_{DS} = 2 V, I_D = 10 mA set (Non-RF),	+11	dBm
Power		f = 2 GHz		

TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

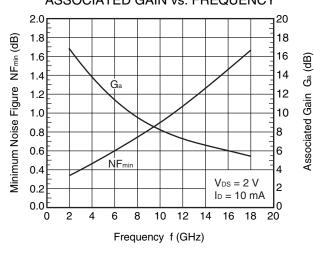
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



DRAIN CURRENT vs. GATE TO SOURCE VOLTAGE

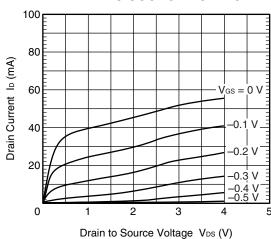


MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. FREQUENCY



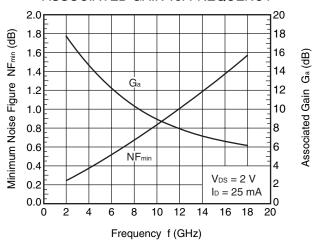
Remark The graphs indicate nominal characteristics.

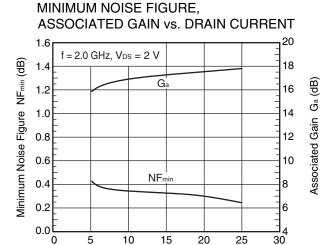
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



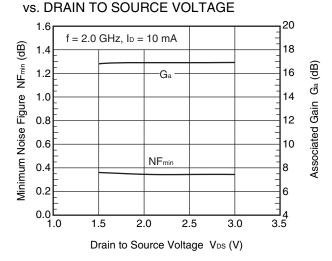
Diam to Source voltage VDS (V)

MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. FREQUENCY





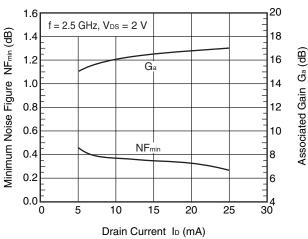
Drain Current I_D (mA)



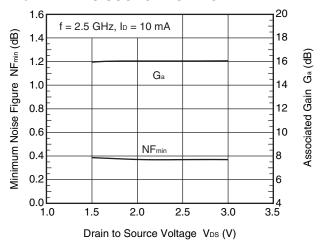
MINIMUM NOISE FIGURE, ASSOCIATED GAIN

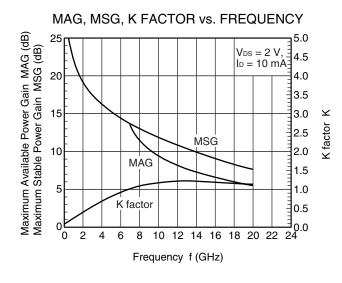
Remark The graphs indicate nominal characteristics.

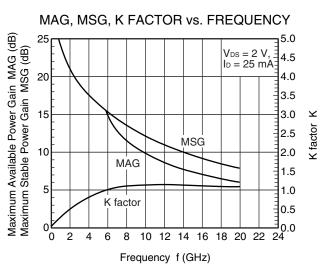
MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN CURRENT



MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN TO SOURCE VOLTAGE

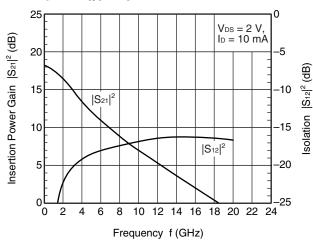




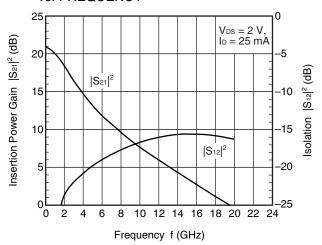


Remark The graphs indicate nominal characteristics.

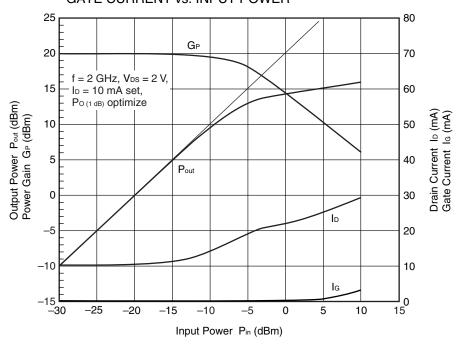
INSERTION POWER GAIN, ISOLATION vs. FREQUENCY



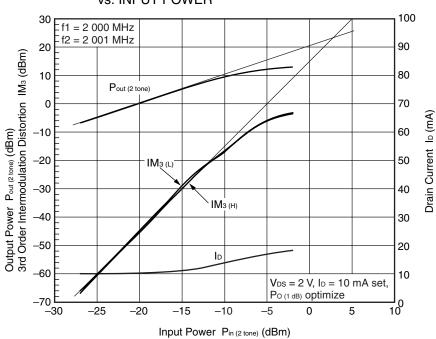
INSERTION POWER GAIN, ISOLATION vs. FREQUENCY



OUTPUT POWER, POWER GAIN, DRAIN CURRENT, GATE CURRENT vs. INPUT POWER



OUTPUT POWER, IM3, DRAIN CURRENT vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

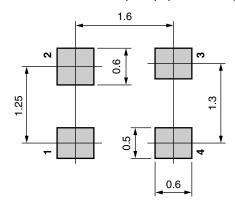
Click here to download S-parameters.

[RF and Microwave] \rightarrow [Device Parameters]

URL http://www2.renesas.com/microwave/en/download.html

MOUNTING PAD LAYOUT DIMENSIONS

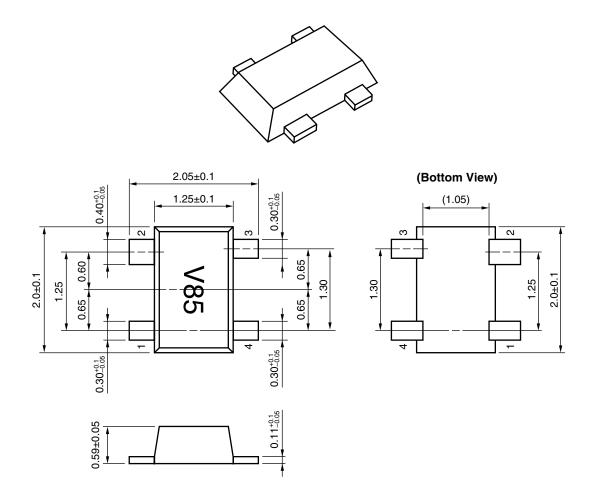
FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)



Remark The mounting pad layout in this document is for reference only.

PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)



PIN CONNECTIONS

- 1. Source
- 2. Drain
- 3. Source
- 4. Gate

Remark (): Reference value

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Revision History

NE3519M04 Data Sheet

		Description	
Rev.	Date	Page	Summary
1.00	Oct 21, 2010	_	First edition issued

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